

Features

- Trench LV MOSFET Technology
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

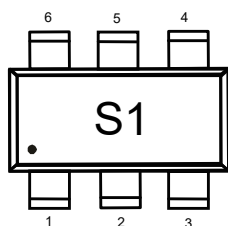
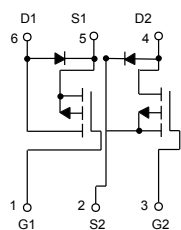
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 100°C/W Junction to Ambient (Note2)

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V _{DS}	-20	V
Gate-Source Voltage		V _{GS}	±8	V
Continuous Drain Current	T _A =25°C	I _D	-2.3	A
	T _A =100°C		-1.4	
Pulsed Drain Current ^(Note3)		I _{DM}	-9.2	A
Total Power Dissipation ^(Note4)		P _D	1.25	W

Note:

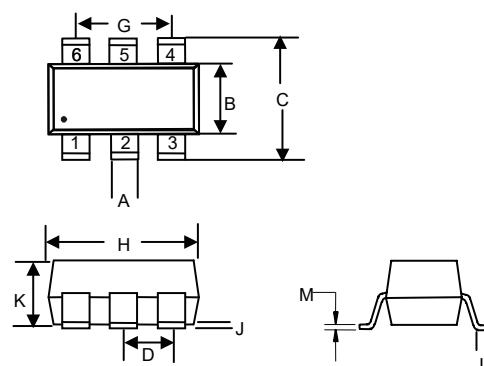
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

Internal Structure and Marking Code



Dual P-Channel MOSFET

SOT23-6L



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.012	0.020	0.30	0.50	
B	0.051	0.070	1.30	1.80	
C	0.087	0.126	2.20	3.20	
D	0.037		0.95		TYP.
G	0.074		1.90		TYP.
H	0.106	0.122	2.70	3.10	
J	0.002	0.006	0.05	0.15	
K	0.030	0.051	0.75	1.30	
L	0.012	0.024	0.30	0.60	
M	0.003	0.008	0.08	0.22	

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-20			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±8V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V			-1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.4	-0.7	-1.0	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-2.5A		50	90	mΩ
		V _{GS} =-2.5V, I _D =-2A		64	125	
		V _{GS} =-1.8V, I _D =-1.6A		110	200	
Forward Tranconductance	g _{FS}	V _{DS} =-5V, I _D =-2.3A		10		S
Gate Resistance	R _g	f=1 MHz, Open drain		14		Ω
Diode Characteristics						
Continuous Body Diode Current	I _S				-2.3	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-0.7A			-1.2	V
Reverse Recovery Time	t _{rr}	I _F =-1.4A,di/dt=100A/μs		16		ns
Reverse Recovery Charge	Q _{rr}			4.7		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =-15V,V _{GS} =0V,f=1MHz		480		pF
Output Capacitance	C _{oss}			61		
Reverse Transfer Capacitance	C _{rss}			51		
Total Gate Charge	Q _g	V _{DS} =-10V,V _{GS} =-4.5V,I _D =-1.4A		8		nC
Gate-Source Charge	Q _{gs}			1.4		
Gate-Drain Charge	Q _{gd}			1.6		
Turn-On Delay Time	t _{d(on)}	V _{DD} =-10V, V _{GS} =-4.5V, R _G =6Ω, I _D =-1.4A		8		ns
Turn-On Rise Time	t _r			9		
Turn-Off Delay Time	t _{d(off)}			26		
Turn-Off Fall Time	t _f			10		

Curve Characteristics

Fig.1 - Typical Output Characteristics

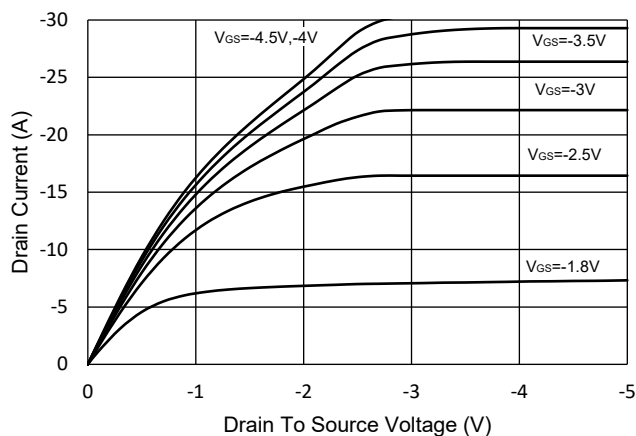


Fig.2 - Transfer Characteristic

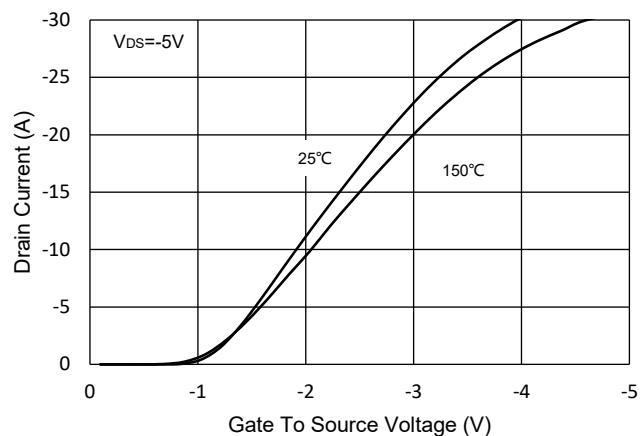


Fig.3 - $R_{DS(ON)} - V_{GS}$

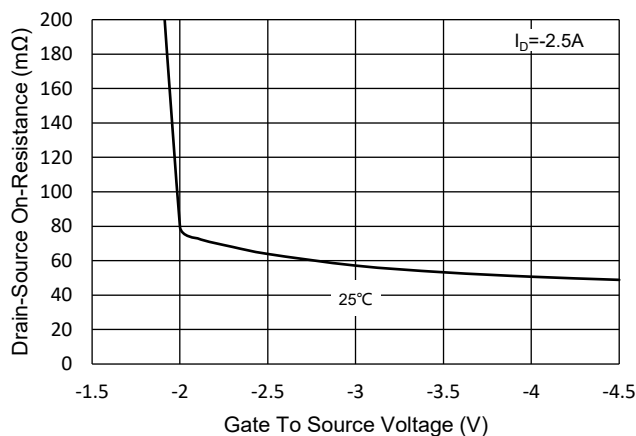


Fig.4 - $R_{DS(ON)} - I_D$

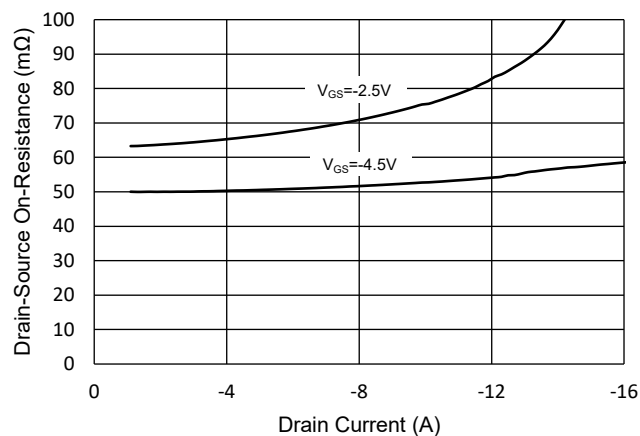


Fig.5 - Capacitance Characteristics

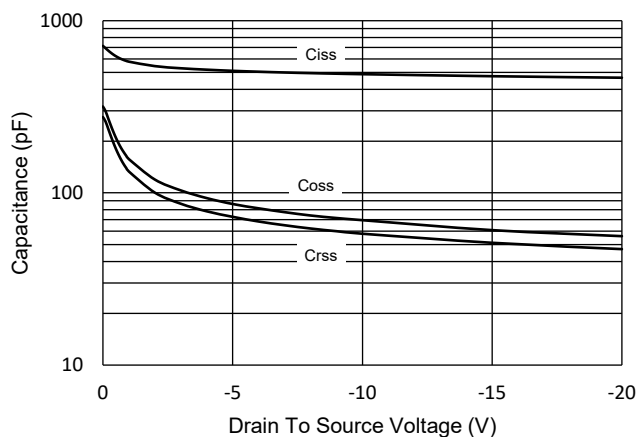
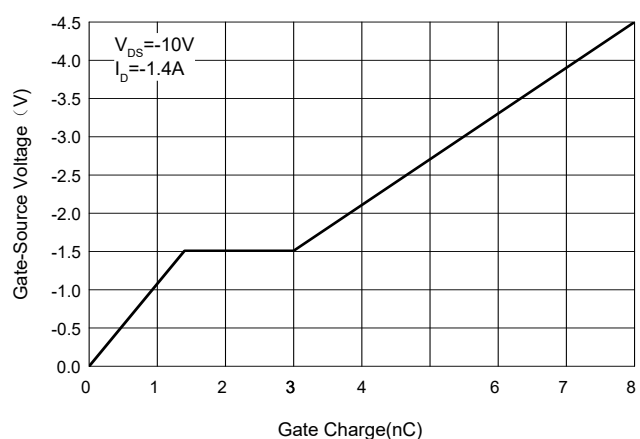


Fig.6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

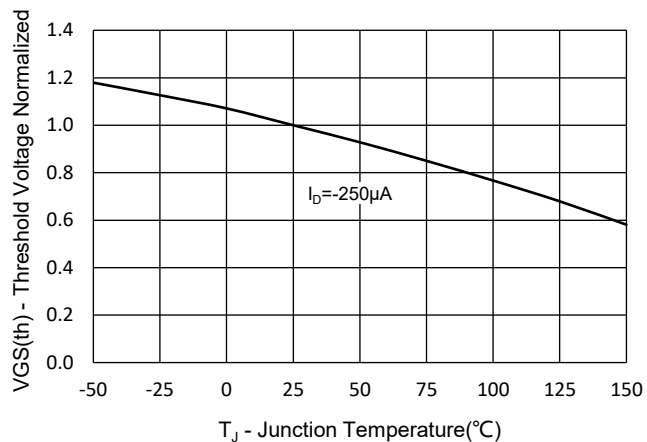


Fig.8 - Normalized On Resistance Characteristics

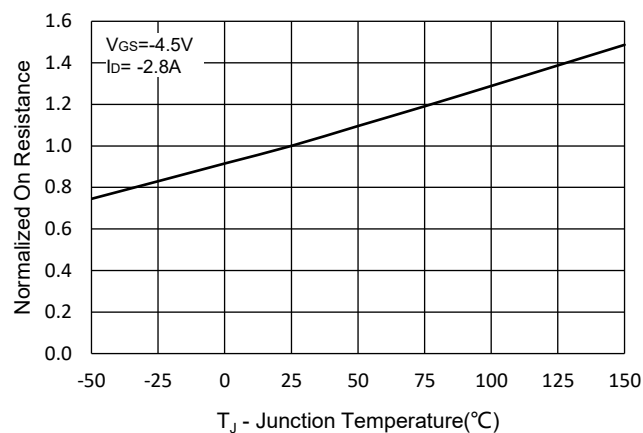


Fig.9 - $I_S - V_{SD}$

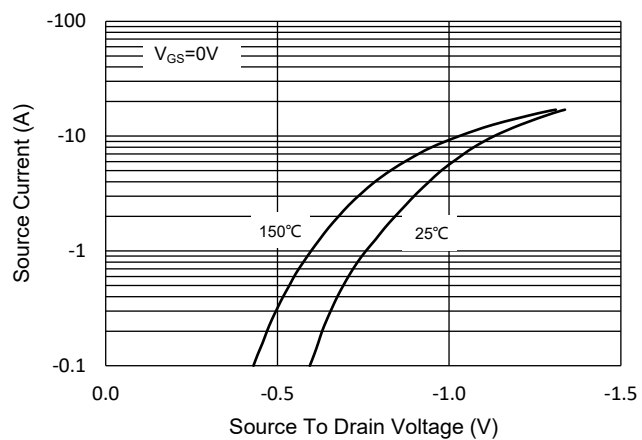


Fig.10 - Drain Current

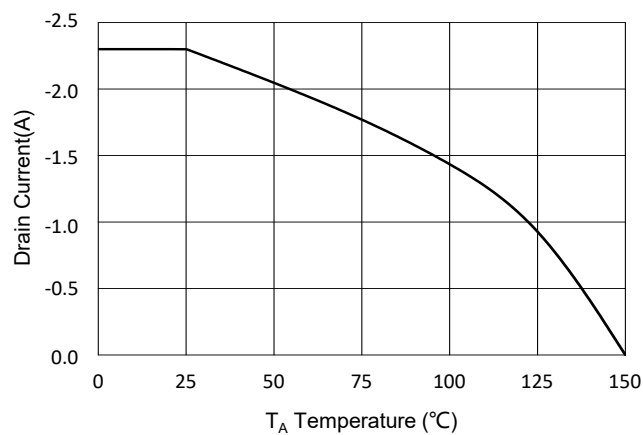
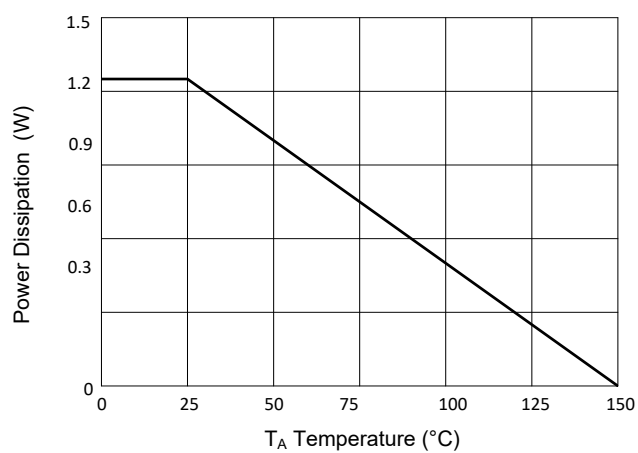


Fig.11 - PD Dissipation



Curve Characteristics

Fig.12 - Safe Operation Area

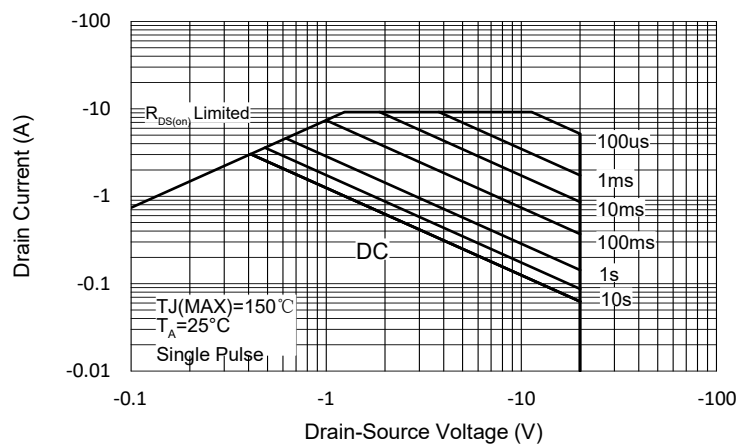
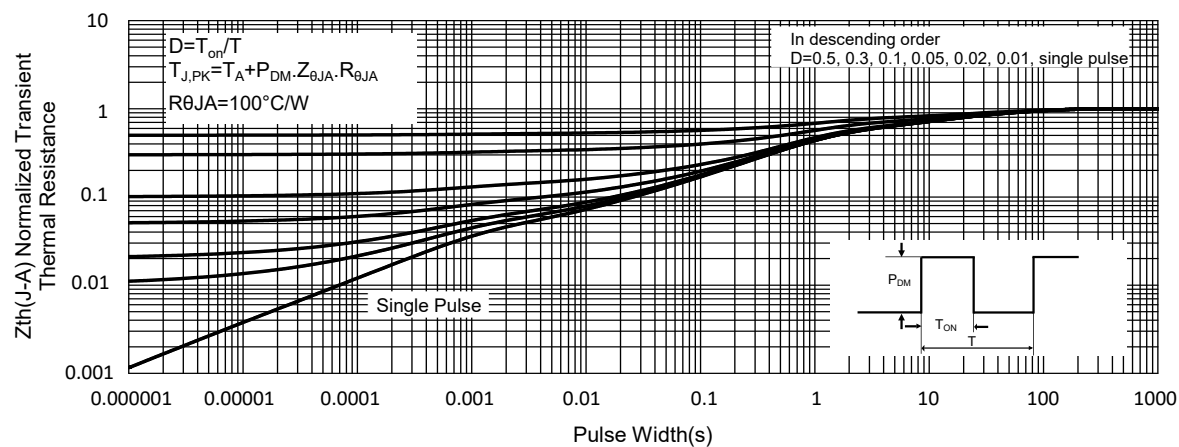


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

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